## NSN 5961-01-023-2822

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View Online at https://aerobasegroup.com/nsn/5961-01-023-2822 **Inclosure Material:** Metal **Overall Length:** 1.330 inches **Overall Diameter:** 0.687 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-61 **Mounting Method:** Threaded stud **Overall Width Across Flats:** Between 0.667 inches and 0.687 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 100.0 collector to base voltage/static/emitter open and 80.0 collector-to-emitter, substaining voltage, base open-circuited and 6.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 30.00 amperes source cutoff current **Power Rating Per Characteristic:** 67.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 82577-928851 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

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